NSN 5962-00-185-8663



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-00-185-8663 **Body Length:** Between 0.340 inches and 0.440 inches **Body Width:** Between 0.265 inches and 0.325 inches **Body Height:** Between 0.030 inches and 0.075 inches **Maximum Power Dissipation Rating:** 625.0 milliwatts **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 58404091248 **Features Provided:** Hermetically sealed and monolithic and negative outputs and positive outputs and w/enable and programmable and programmed and bipolar and w/buffered output and w/decoded output and expandable and wire-or outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Test Data Document:

05869-717383 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 flat leads

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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